TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# HN1K05FU

For Portable Devices
High Speed Switching Applications
Interface Applications

- High input impedance and extremely low drive current.
- Vth is low and it is possible to drive directly at low-voltage CMOS. : Vth = 0.5 to 1.0 V
- Suitable for high-density mounting because of a compact package.

### Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage	$V_{DS}$	20	V	
Gate-source voltage	$V_{GSS}$	10	V	
DC drain current	I <sub>D</sub>	100	mA	
Drain power dissipation	P <sub>D</sub> (Note)	200	mW	
Channel temperature	T <sub>ch</sub>	150	°C	
Storage temperature range	T <sub>stg</sub>	–55 to 150	°C	

Note: TOTAL rating

# 1. SOURCE 1 4. SOURCE 2 2. GATE 1 5. GATE 2 3. DRAIN 2 6. DRAIN 1 US6 JEDEC — JEITA — TOSHIBA 2-2J1C

Weight: 6.8 mg

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0 V	_	_	1	μА	
Drain-source breakdown voltage	V (BR) DSS	$I_D = 100 \mu A, V_{GS} = 0 V$	20	_	_	V	
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V	_	_	1	μА	
Gate threshold voltage	V <sub>th</sub>	$V_{DS} = 1.5 \text{ V}, I_D = 0.1 \text{ mA}$	0.5	_	1	V	
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 1.5 \text{ V}, I_D = 10 \text{ mA}$	35	70	_	mS	
Drain-Source ON resistance 1	R <sub>DS</sub> (ON) 1	$I_D = 1 \text{ mA}, V_{GS} = 1.2 \text{ V}$	_	15	50	Ω	
Drain-Source ON resistance 2	R <sub>DS</sub> (ON) 2	$I_D = 10 \text{ mA}, V_{GS} = 1.5 \text{ V}$	_	10	40	Ω	
Drain-Source ON resistance 3	R <sub>DS (ON) 3</sub>	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	7	28	Ω	
Input capacitance	C <sub>iss</sub>	$V_{DS} = 1.5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	12	_	pF	
Reverse transfer capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 1.5 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	3.4	_	pF	
Output capacitance	Coss	V <sub>DS</sub> = 1.5 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	12	_	pF	
Switching time	t <sub>on</sub>	$V_{DD} = 1.5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 1.5 \text{ V}$	_	0.35	_	0	
	t <sub>off</sub>	$V_{DD} = 1.5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 1.5 \text{ V}$	—	0.2		μS	

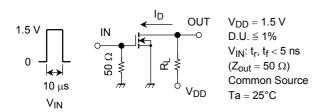
# **Equivalent Circuit (top view)**

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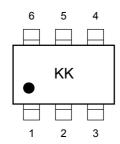
(Q1, Q2 common)

# **Switching Time Test Circuit**

# (a) Test circuit

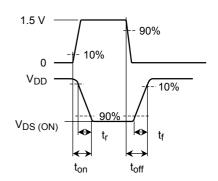


# Marking

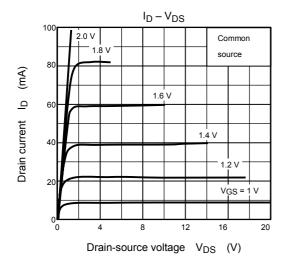


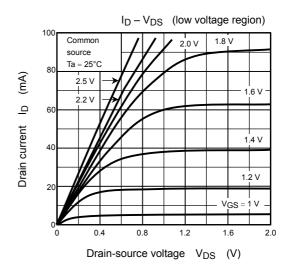
(b)  $V_{IN}$   $V_{GS}$ 

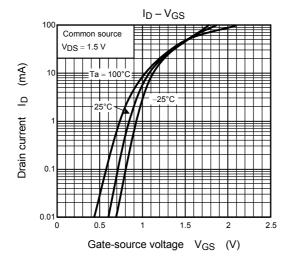
(c)  $V_{\rm OUT}$   $V_{\rm DS}$ 

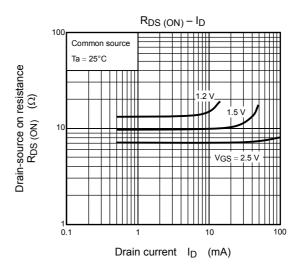


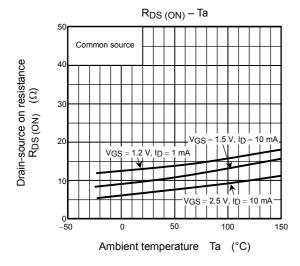
(Q1, Q2 common)

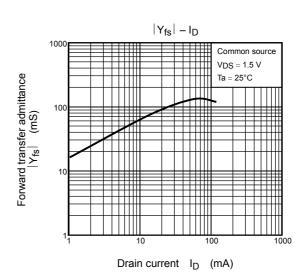






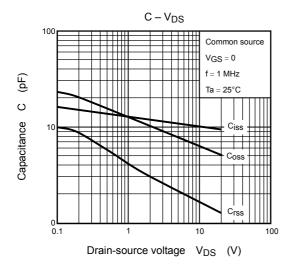


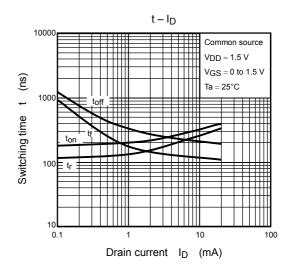


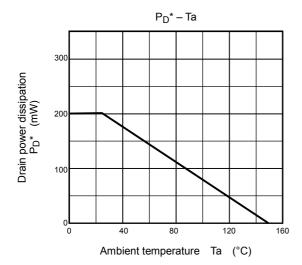


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(Q1, Q2 common)







\*: TOTAL rating

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